Freescale Semiconductor Technical Data

MHL21336 Rev. 4, 1/2005

Will be replaced by MHL21336N in March 2005. There are no form, fit or function changes with this part replacement. N suffix added to part number to indicate transition to lead-free terminations.

3G Band RF Linear LDMOS Amplifier

Designed for ultra-linear amplifier applications in 50 ohm systems operating in the 3G frequency band. A silicon FET Class A design provides outstanding linearity and gain. In addition, the excellent group delay and phase linearity characteristics are ideal for digital CDMA modulation systems.

• Third Order Intercept: 45 dBm Typ

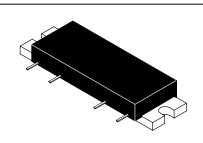
INFORMAT

3CHIVE

- Power Gain: 31 dB Typ (@ f = 2140 MHz)
- Excellent Phase Linearity and Group Delay Characteristics
- Ideal for Feedforward Base Station Applications



2110-2170 MHz 3.0 W, 31 dB RF LINEAR LDMOS AMPLIFIER



CASE 301AP-02, STYLE 1

Table 1. Absolute Maximum Ratings ($T_C = 25^{\circ}C$ unless otherwise noted)

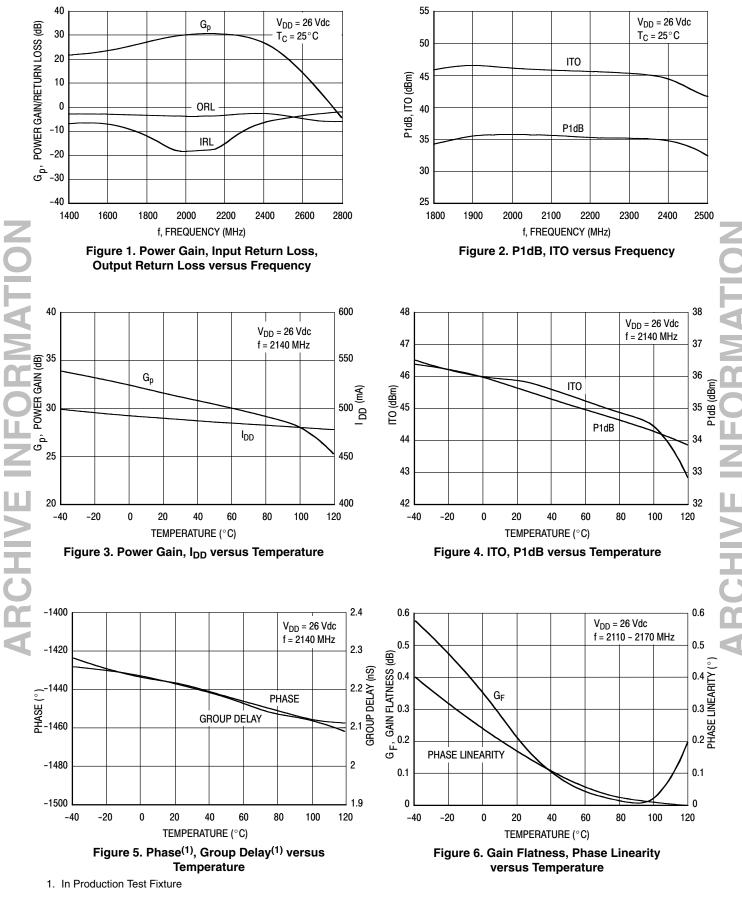
Rating	Symbol	Value	Unit
DC Supply Voltage	V _{DD}	30	Vdc
RF Input Power	P _{in}	+5	dBm
Storage Temperature Range	T _{stg}	- 40 to +100	°C
Operating Case Temperature Range	T _C	- 20 to +100	°C

Table 2. Electrical Characteristics (V_{DD} = 26 Vdc, T_C = 25°C; 50 Ω System)

Characteristic		Symbol	Min	Тур	Max	Unit
Supply Current		I _{DD}	—	500	525	mA
Power Gain	(f = 2140 MHz)	Gp	30	31	32	dB
Gain Flatness	(f = 2110 - 2170 MHz)	G _F	—	0.15	0.4	dB
Power Output @ 1 dB Comp.	(f = 2140 MHz)	P _{out} 1 dB	34	35	_	dBm
Input VSWR	(f = 2110 - 2170 MHz)	VSWR _{in}	—	1.2:1	1.5:1	
Third Order Intercept (f1 = 2137 MHz, f2 = 2	142 MHz)	ITO	44	45	_	dBm
Noise Figure	(f = 2170 MHz)	NF	—	4.5	5	dB

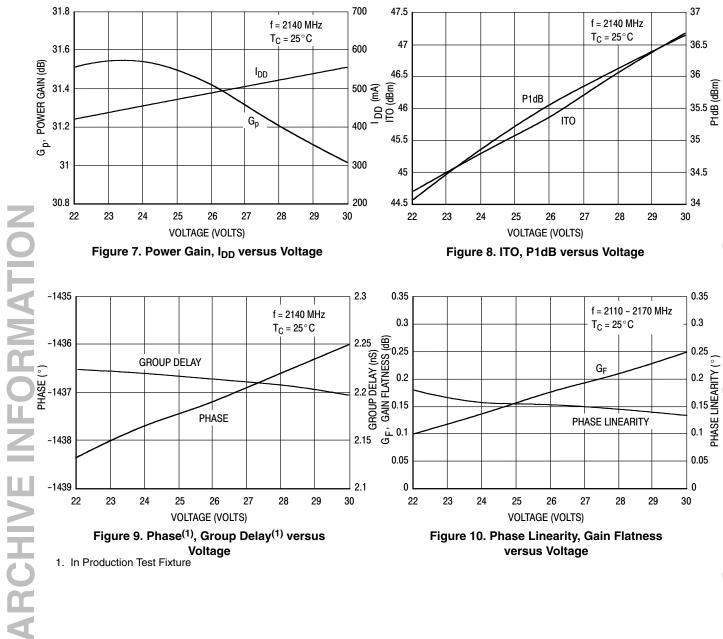


TYPICAL CHARACTERISTICS



MHL21336

TYPICAL CHARACTERISTICS



MHL21336

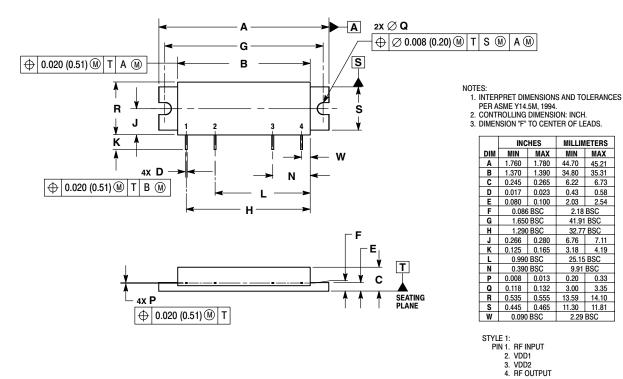
NOTES

ARCHIVE INFORMATION

NOTES

NOTES

PACKAGE DIMENSIONS



CASE 301AP-02 ISSUE C

RF Device Data

Freescale Semiconductor

MILLIMETERS

0.43 0.58

2.03 2.54

2.18 BSC

41.91 BSC

32.77 BSC

6.76 7.11 3.18 4.19

25.15 BSC

9.91 BSC

2.29 BSC

CASE: GROUND

0.20 0.33 3.00 3.35

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